



# High Performance Two-Color One Megapixel CMOS ROIC for QWIP Detectors

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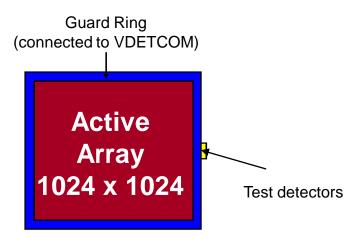
### **ROIC Overview**

- Name: ISC0501
- Format: 1024 x 1024 pixels (1 megapixel)
- Pixel Pitch: 30µm
- Detectors: GaAs / AlGaAs QWIPs
- Two-color
  - MWIR (4-5μm) & LWIR (8-9μm)
  - One detector of each color per 30µm pixel
    - · 2 colors are pixel co-located
  - Separate signal paths for each color for optimization of:
    - Detector bias
    - Integration time
    - Offsets
    - Gains
  - Simultaneous readout of pixel data from both colors
- Frame Rate: 60Hz for full frame readout of both colors
  - 5MHz input clock
  - 10MHz pixel rate output on 8 analog outputs per color
- Operating temperature 60K to 77K
  - Functional at 300K for testing purposes



### **Detector Interface: Overview**

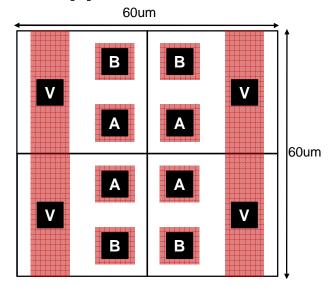
- Array of 1030 x 1030 pixels
  - Active array is the center 1024 x 1024 pixels
  - Guard ring of 3 pixels around active array
    - All pad openings in guard ring are tied to the detector common bias (VDETCOM bias) on the ROIC
- 4 Test detectors outside of the VDETCOM guard ring on the right side of the array
  - All pad openings in test detector pixels are wired to 100µm x 100µm pads for probing





### **Detector Interface: Unit Cells**

- Three pad opening per unit cell (pixel)
  - A: Connects one terminal of MWIR QWIP detector to ROIC signal path A
  - B: Connects one terminal of LWIR QWIP detector to ROIC signal path B
  - V: Connects shared terminal between the QWIPs to global detector common bias (VDETCOM)
- Unit cells are mirrored in X and Y to make a super unit cell
- Super unit cells are stepped in both X and Y



"Super Unit Cell"
Composed of 4 unit cells mirrored in X and Y
Top metal layer (red); pad openings (black)



## **Analog Design: Overview**

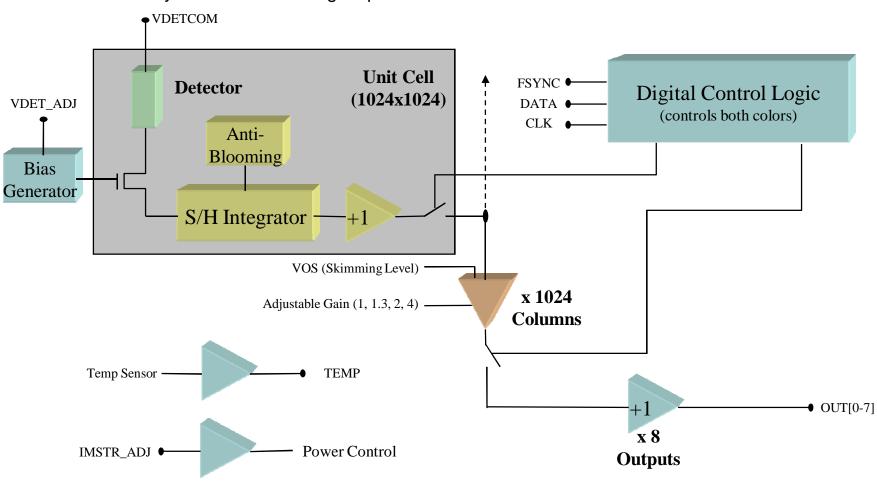
- Analog signal path buffers and pre-processes the detector signal from the detector to the output of the ROIC
  - Separate set of circuitry for each color from the detector interface in each unit cell through the output drivers
  - Controls available in the logic to independently adjust each color's signal path



## **Analog Design: Signal Path**

#### Signal path shown for one color

Circuitry for two identical signal paths exists on the ISC0501 ROIC





## **Analog Design: Unitcell**

#### Detector bias voltage

- Adjustable independently per color
- Adjustments can be made through the VDET\_ADJA and VDET\_ADJB pads
- Adjustments can also be made through the serial control register if the VDET\_ADJ\* pads are left floating

#### Direct injection (DI) input circuit

- Sets detector bias
- Allows detector current to flow into the ROIC
- Low power
- Small circuit size allows for high charge storage capability

## Separate integration capacitors in each signal path to integrate and store detector signal

- MWIR (color A): ~4.2 million electrons charge capacity
- LWIR (color B): ~16.7 million electrons charge capacity

#### Anti-blooming circuitry

- Prevents high detector current from de-biasing the detector
- Circuitry in unitcell designed for snapshot integration in two modes
  - Integrate-Then-Read (ITR)
  - Integrate-While-Read (IWR)

#### Data sent out of the unit cell through a column buffer

Read out of unit cell during the line time in a pipelined fashion



## **Analog Design: Column Amplifier**

- Voltage mode column amplifier allows for analog signal processing in the ROIC signal path
- Adjustable gain per color
  - 1.0x, 1.3x, 2.0x or 4.0x
  - Set using the serial control register
- Adjustable offset (skimming) per color
  - Skimming is used to remove detector dark current
  - When on, skimming level set using pads
    - MWIR skimming: VOSA pad
    - LWIR skimming: VOSB pad
  - Turned on / off using the serial control register
- Adjustable reference level of column amplifier to optimize range and linearity of the analog signal path
  - MWIR reference level: VREFA pad
  - LWIR reference level: VREFB pad



## **Analog Design: Output Drivers**

- Eight analog output drivers per color
  - Pixel rate of up to 10MHz
  - Option to only turn on 4 output drivers per color
    - · Set in serial control register
- Data of each pixel is sent out simultaneously for color A and color B
- During line dead time outputs are set to a reference level
  - VOUTREFA1 is the MWIR reference level during odd rows
  - VOUTREFA2 is the MWIR reference level during even rows
  - VOUTREFB1 is the LWIR reference level during odd rows
  - VOUTREFB2 is the LWIR reference level during even rows
- Optional reference output for each color
  - Allows common mode noise to be subtracted at the system level at the expense of increased ROIC noise and increased ROIC power
  - Input to the reference circuitry:
    - VOUTREFA1 is the MWIR reference circuit input during odd rows
    - VOUTREFA2 is the MWIR reference circuit input during even rows
    - VOUTREFB1 is the LWIR reference circuit input during odd rows
    - VOUTREFB2 is the LWIR reference circuit input during even rows
  - Turned on / off through serial control register



## **Analog Design: Adjustability**

- Analog signal path can be optimized and tested through the serial control register and external pads
  - All adjustments previously described in analog signal path
  - Power adjustments
    - IMSTR\_ADJA: Global adjust of power for MWIR from pad
    - IMSTR\_ADJB: Global adjust of power for LWIR from pad
    - Can adjust power of each color independently through the serial control register
  - Power adjustments are not typically necessary
    - Can be used during initial testing of the ROIC
    - Advanced users can optimize power and performance of the analog signal path



## **Digital Design: Overview**

- Digital design is used to control the functions of the ROIC
  - Provides an interface to the chip to control the operating modes
  - Controls the flow and multiplexing of each color's analog signal path



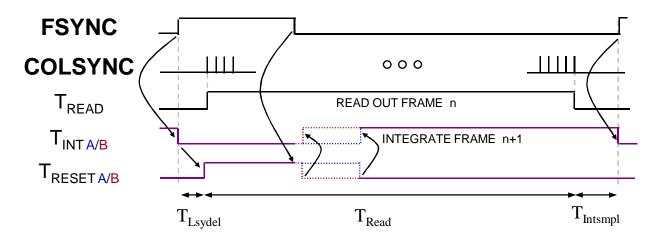
## Digital Design: User Interface

- Control word applied through a serial control register sets the operating mode of the ROIC
  - "Start" bit begins reading in the control register word
  - 127-bit long word
  - One word per frame
  - If no word is sent during a frame, the setting of the previous frame remains unchanged
- Command Register Controls The Following Functions:
  - On-Chip Bias Control
  - Skimming Enable ( per color )
  - Gain Control ( per color )
  - Detector Bias Adjustment (per color)
  - Reference Output Enable
  - Anti-Bloom Enable
  - Variable Line Dead Time
  - Integration Times ( per color )
  - Row Windowing Size / Row Windowing Location
  - Invert Mode
  - Integration Mode
  - Output Mode
  - Test Row
  - Programmable Test
  - Global Reset

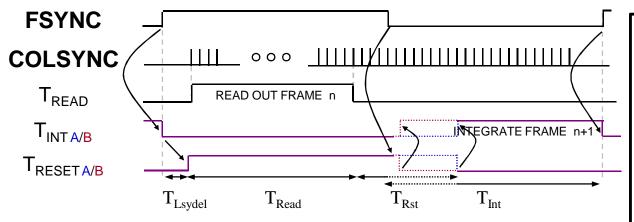


## Digital Design: ITR & IWR Integration / Readout Modes

Integrate While Read: Fastest frame rate but reduced performance



Integrate Then Read: Slower frame rate with increased performance

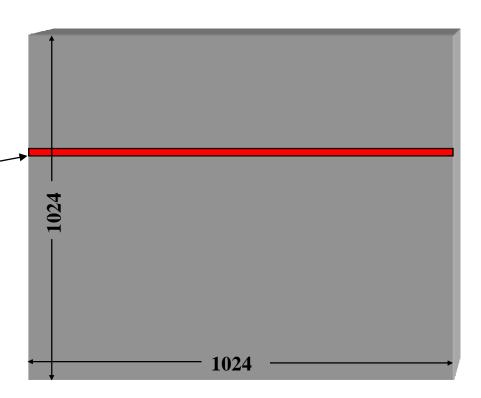


Differences in integration times between the two colors are set through bits in the serial command register in both ITR and IWR modes



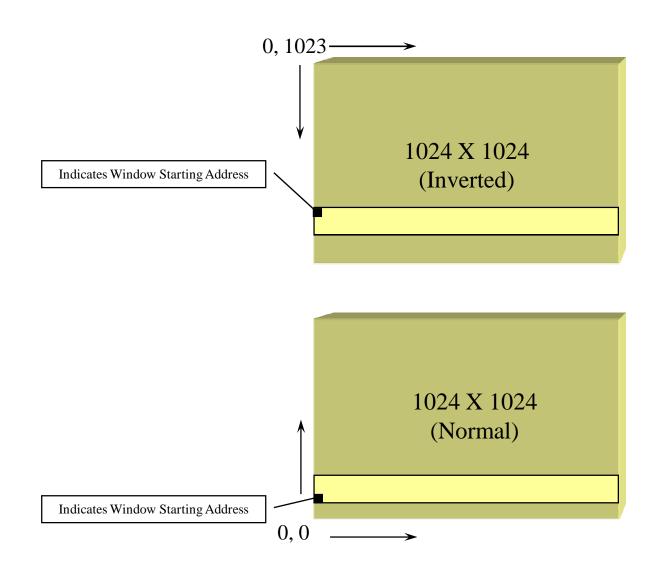
## Digital Design: Windowing Operation

- Windowing In Row Dimension Only
- Window Size and Location Resolution Of 1 Row
- Smallest Window
  - -1024x1
  - Readout Rate = 3,366Hz
    - 170us Integration Time (IWR)





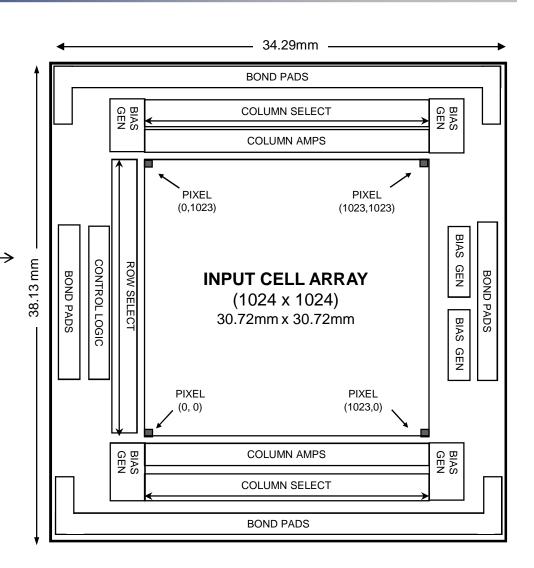
## Digital Design: Readout Order





## Physical Design: Overview

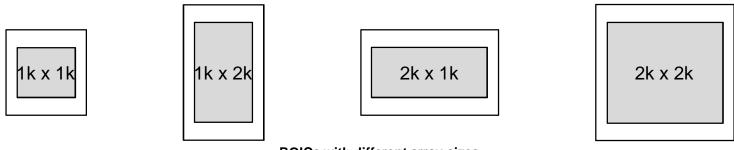
- Standard CMOS mixed signal process
  - 0.5µm transistors
- Die size of 34.29mm x 38.13mm
  - 16 die per 8-inch wafer
- Block diagram of layout
  - Not to scale





## Physical Design: Modular Layout

- Circuitry and layout designed to allow for expandability from 1k x
   1k array to up to 2k x 2k
  - As size increases in the X direction the number of output drivers of each color increases
  - An ROIC with 2048 rows must set a bit in the serial control register to allow correct row windowing and scanning
- Decreased performance with larger array sizes
  - Increase power
  - Decreased maximum input clock rate and maximum output data rate
  - Decreased frame rate
  - Reduced image performance
- Arrays sizes other than 1k x 1k have yet to be fabricated or tested



ROICs with different array sizes

Active array in gray. Pictures not to scale.



## **Performance: Test Results**

- Characterization was completed on the ISC0501 ROIC at 77K
- Only Linearity in IWR did not meet specification

Function	Test Results	Compliance
Full Scale Swing	≥ 2.0V	YES
Linearity ITR	Less than Spec	YES
Linearity IWR	Slightly above Spec	NO
Multiple Outputs	4 or 8 per color	YES
Invert	Reverse row order	YES
Power	≤600mW 8 output	YES
Power Adjust	Functional	YES
Windowing	Functional	YES
Integration Mode	ITR and IWR	YES
Integration Control	Adjustable per color	YES
Detector Bias	Functional	YES
Temperature Diode	0.7V ±0.05V @300K 1.07V ±0.05V @77K	YES
Reference Output	Functional	YES
Noise (MWIR/A)	Less than Spec	YES
Noise (LWIR/B)	Less than Spec	YES
Data Rate	≥ 10MHz	YES
Gain	1x, 1.3x, 2x, 4x	YES
Skimming	Functional	YES
Adjust line time	Functional	YES
Crosstalk color to color	Less than Spec	YES
Crosstalk	Less than Spec	YES



## Performance: Image from FPA using the ISC0501 ROIC

 FPA developed by JPL using the ISC0501 ROIC hybridized with JPL's QWIP detectors



MWIR:
Ability to see hot CO<sub>2</sub> gas in
MWIR band, creating a longer
looking fame

LWIR:
Readout at the same time as the MWIR image, but CO<sub>2</sub> gas is not detected in LWIR band



## **Summary**

- Two-color one megapixel ROIC provides a user with large amounts of data not available with older generation ROICs
  - ISC0501 two-color 1k x 1k

HDTV

1-color standard format ROIC standard black and white





- Extra information makes each object more distinct
  - Faster and easier detection of objects
  - Applications in military, medical, geological, astronomy and commercial fields
- All two-color circuitry is designed at the QWIP detector level and the ROIC level
  - Reduced complexity at system level → reduced cost at system level
- Large set of adjustments on ISC0501 ROIC
  - Allows for an FPA to be produced to that can meet requirements and be optimized for many different applications